

Single-chip Type with built-in FET Switching Regulator Series

# Flexible Step-down Switching Regulators with Built-in Power MOSFET



BD9006F/HFP, BD9007F/HFP, BD9009HFP

No.12027ECT35

## ● Overview

The high-accuracy frequency flexible step-down switching regulator is a switching regulator with built-in POWER MOS FET, which withstands high pressure. The operational frequency is freely configurable with external resistance. It features a wide input voltage range (7V~35V) and a high frequency accuracy of  $\pm 5\%$  (BD9006F/HFP, BD9009HFP,  $f=200\sim 500\text{kHz}$ ), Furthermore, an external synchronization input pin enables synchronous operation with external clock.

## ● Features

- 1) Minimal external components
- 2) Wide input voltage range: 7V~35V
- 3) Frequency voltage accuracy:  $\pm 5\%$ (BD9006F/HFP, BD9009HFP,  $f=200\sim 500\text{kHz}$ )  
 $\pm 20\%$ (BD9007F/HFP)
- 4) Built-in P-ch POWER MOS FET
- 5) Output voltage setting enabled with external resistor: 0.8V~ $V_{IN}$
- 6) Reference voltage accuracy: 0.8V $\pm 2\%$
- 7) Wide operating temperature range:  $-40^{\circ}\text{C}\sim +105^{\circ}\text{C}$
- 8) Low dropout: 100% ON duty cycle
- 9) Standby mode supply current: 0 $\mu\text{A}$  (Typ.)
- 10) Oscillation frequency variable with external resistor: 50~500kHz
- 11) External synchronization enabled
- 12) Soft start function: soft start time fixed to 5ms (Typ.)
- 13) Built-in overcurrent protection circuit
- 14) Built-in thermal shutdown protection circuit
- 15) High-power HRP7 package mounted (BD9006HFP, BD9007HFP, BD9009HFP)
- 16) Compact SOP8 package mounted (BD9006F, BD9007F)

## ● Applications

All fields of industrial equipment, such as Flat TV, printer, DVD, car audio, car navigation, and communication such as ETC, AV, and OA.

## ● Product lineup

| Item                           | BD9006F/HFP                                    | BD9007F/HFP                                    | BD9009HFP                                      |
|--------------------------------|--|--|--|
| Output Current                 | 2A   | 2A   | 4A   |
| Input Range                    | 7V~35V   | 7V~35V   | 7V~35V   |
| Oscillation Frequency Range    | 50~500kHz                                      | 50~500kHz                                      | 50~500kHz                                      |
| Oscillation Frequency Accuracy | $\pm 5\%$                                      | $\pm 20\%$                                     | $\pm 5\%$                                      |
| External Synchronous Function  | Provided                                       | Provided                                       | Provided                                       |
| Standby Function               | Provided                                       | Provided                                       | Provided                                       |
| Operating Temperature          | $-40^{\circ}\text{C}\sim +105^{\circ}\text{C}$ | $-40^{\circ}\text{C}\sim +105^{\circ}\text{C}$ | $-40^{\circ}\text{C}\sim +105^{\circ}\text{C}$ |
| Package                        | SOP8/HRP7                                      | SOP8/HRP7                                      | HRP7   |

## ● Absolute Maximum Ratings (Ta=25°C)

| Parameter                    |                          | Symbol         | Limits   | Unit |
|------------------------------|--------------------------|----------------|----------|------|
| Power Supply Voltage         |                          | VIN            | 36       | V    |
| Output Switch Pin Voltage    |                          | VSW            | VIN      | V    |
| Output Switch Current        | BD9006F/HFP, BD9007F/HFP | ISW            | 2 *1     | A    |
|                              | BD9009HFP                |                | 4 *1     |      |
| EN/SYNC Pin Voltage          |                          | VEN/SYNC       | VIN      | V    |
| RT, FB, INV Pin Voltage      |                          | VRT, VFB, VINV | 7        |      |
| Power Dissipation            | HRP7                     | Pd             | 5.5 *2   | W    |
|                              | SOP8                     |                | 0.69 *3  | W    |
| Operating Temperature Range  |                          | Topr           | -40~+105 | °C   |
| Storage Temperature Range    |                          | Tstg           | -55~+150 | °C   |
| Maximum Junction Temperature |                          | Tjmax          | 150      | °C   |

\*1 Should not exceed Pd-value.

\*2 Reduce by 44mW/°C over 25°C, when mounted on 2-layer PCB of 70x70x1.6mm<sup>3</sup>  
(PCB incorporates thermal via. Copper foil area on the reverse side of PCB: 10.5x10.5mm<sup>2</sup>)\*3 Reduce by 5.52mW/°C over 25°C, when mounted on 2-layer PCB of 70x70x1.6mm<sup>3</sup>

## ● Recommended Operating Range

| Parameter                            | BD9006F/HFP | BD9007F/HFP | BD9009HFP | Unit |
|--------------------------------------|-------------|-------------|-----------|------|
| Operating Power Supply Voltage       | 7~35        | 7~35        | 7~35      | V    |
| Output Switch Current                | ~2          | ~2          | ~4        | A    |
| Output Voltage (min pulse width)     | 250         | 250         | 360       | ns   |
| Oscillation Frequency                | 50~500      | 50~500      | 50~500    | kHz  |
| Oscillation Frequency set Resistance | 27~360      | 27~360      | 27~360    | kΩ   |

## ● Possible Operating Range

| Parameter                      | BD9006F/HFP | BD9007F/HFP | BD9009HFP | Unit |
|--------------------------------|-------------|-------------|-----------|------|
| Operating Power Supply Voltage | 5~35        | 5~35        | 5~35      | V    |

## ● Electrical Characteristics

◎BD9006F/HFP (Unless otherwise specified, Ta=25°C, VIN=13.2V, VEN/SYNC=5V)

| Parameter  | Symbol    | Spec Values |       |       | Unit | Conditions                        |
|--|-----------|-------------|-------|-------|------|-----------------------------------|
|  |           | Min.        | Typ.  | Max.  |      |                                   |
| Standby Circuit Current                            | ISTB      | -           | 0     | 10    | μA   | VEN/SYNC=0V                       |
| Circuit Current                                    | IQ        | -           | 4     | 6.5   | mA   | IO=0A, RT=51kΩ, VINV=0.7V         |
| 【SW Block】   |           |             |       |       |      |                                   |
| POWER MOS FET ON Resistance                        | RON       | -           | 0.3   | 0.6   | Ω    | ISW=50mA                          |
| Operating Output Current Of Overcurrent Protection | IOLIMIT   | 2           | 4     | -     | A    |                                   |
| Output Leak Current                                | IOLAK     | -           | 0     | 30    | μA   | VIN=35V, VEN/SYNC=0V              |
| 【Error Amp Block】                                  |           |             |       |       |      |                                   |
| Reference Voltage 1                                | VREF1     | 0.784       | 0.800 | 0.816 | V    | VFB=VINV                          |
| Reference Voltage 2                                | VREF2     | 0.780       | 0.800 | 0.820 | V    | VIN=10~16V, VFB=VINV              |
| Reference Voltage Input Regulation                 | ΔVREF     | -           | 0.5   | -     | %    |                                   |
| Input Bias Current                                 | IB        | -1          | -     | -     | μA   | VINV=0.6V                         |
| Maximum FB Voltage                                 | VFBH      | 2.2         | 2.4   | -     | V    | VINV=0V                           |
| Minimum FB Voltage                                 | VFBL      | -           | 0.5   | 0.6   | V    | VINV=2V                           |
| FB Sink Current                                    | IFBSINK   | -0.47       | -1.16 | -2.45 | mA   | VFB=1V, VINV=1V                   |
| FB Source Current                                  | IFBSOURCE | 1           | 5     | 15    | mA   | VFB=1V, VINV=0.6V                 |
| Soft Start Time                                    | TSS       | 3           | 5     | 9     | mS   | Ta=-40~105°C                      |
| 【Oscillator Block】                                 |           |             |       |       |      |                                   |
| Oscillation Frequency                              | FOSC      | 285         | 300   | 315   | kHz  | VIN=7V, RT=51kΩ                   |
| Frequency Input Regulation                         | ΔFOSC     | -           | 0.5   | -     | %    | VIN=7~16V                         |
| 【Enable/Sync Input Block】                          |           |             |       |       |      |                                   |
| Output ON Voltage                                  | VENON     | 2.6         | -     | -     | V    | VEN/SYNC Sweep Up, Ta=-40~105°C   |
| Output OFF Voltage                                 | VENOFF    | -           | -     | 0.8   | V    | VEN/SYNC Sweep Down, Ta=-40~105°C |
| Sink Current                                       | IEN/SYNC  | -           | 35    | 90    | μA   |                                   |
| External Sync Frequency                            | FSYNC     | 495         | 500   | 505   | kHz  | RT=51kΩ, EN/SYNC=500kHz, Duty 50% |

\* Not designed to be radiation resistant.

©BD9007F/HFP (Unless otherwise specified, Ta=25°C, VIN=13.2V, VEN/SYNC=5V)

| Parameter  | Symbol    | Spec Values |       |       | Unit | Conditions                       |
|--|-----------|-------------|-------|-------|------|----------------------------------|
|  |           | Min.        | Typ.  | Max.  |      |                                  |
| Standby Circuit Current                            | ISTB      | -           | 0     | 10    | μA   | VEN/SYNC=0V                      |
| Circuit Current                                    | IQ        | -           | 4     | 6.5   | mA   | IO=0A,RT=51kΩ,VINV=0.7V          |
| 【SW Block】   |           |             |       |       |      |                                  |
| POWER MOS FET ON Resistance                        | RON       | -           | 0.3   | 0.6   | Ω    | ISW=50mA                         |
| Operating Output Current Of Overcurrent Protection | IOLIMIT   | 2           | 4     | -     | A    |                                  |
| Output Leak Current                                | IOLLEAK   | -           | 0     | 30    | μA   | VIN=35V, VEN/SYNC=0V             |
| 【Error Amp Block】                                  |           |             |       |       |      |                                  |
| Reference Voltage 1                                | VREF1     | 0.784       | 0.800 | 0.816 | V    | VFB=VINV                         |
| Reference Voltage 2                                | VREF2     | 0.780       | 0.800 | 0.820 | V    | VIN=10~16V,VFB=VINV              |
| Reference Voltage Input Regulation                 | ΔVREF     | -           | 0.5   | -     | %    |                                  |
| Input Bias Current                                 | IB        | -1          | -     | -     | μA   | VINV=0.6V                        |
| Maximum FB Voltage                                 | VFBH      | 2.2         | 2.4   | -     | V    | VINV=0V                          |
| Minimum FB Voltage                                 | VFBL      | -           | 0.5   | 0.6   | V    | VINV=2V                          |
| FB Sink Current                                    | IFBSINK   | -0.47       | -1.16 | -2.45 | mA   | VFB=1V,VINV=1V                   |
| FB Source Current                                  | IFBSOURCE | 1           | 5     | 15    | mA   | VFB=1V,VINV=0.6V                 |
| Soft Start Time                                    | TSS       | 3           | 5     | 9     | mS   | Ta=-40~105°C                     |
| 【Oscillator Block】                                 |           |             |       |       |      |                                  |
| Oscillation Frequency                              | FOSC      | 240         | 300   | 360   | kHz  | VIN=7V,RT=51kΩ                   |
| Frequency Input Regulation                         | ΔFOSC     | -           | 0.5   | -     | %    | VIN=7~16V                        |
| 【Enable/Sync Input Block】                          |           |             |       |       |      |                                  |
| Output ON Voltage                                  | VENON     | 2.6         | -     | -     | V    | VEN/SYNC Sweep Up,a=-40~105°C    |
| Output OFF Voltage                                 | VENOFF    | -           | -     | 0.8   | V    | VEN/SYNC Sweep,own,Ta=-40~105°C  |
| Sink Current                                       | IEN/SYNC  | -           | 35    | 90    | μA   |                                  |
| External Sync Frequency                            | FSYNC     | 495         | 500   | 505   | kHz  | RT=51kΩ, EN/SYNC=500kHz,Duty 50% |

\* Not designed to be radiation resistant.

©BD9009HFP (Unless otherwise specified, Ta=25°C, VIN=13.2V, VEN/SYNC=5V)

| Parameter  | Symbol    | Spec Values |       |       | Unit | Conditions                       |
|--|-----------|-------------|-------|-------|------|----------------------------------|
|  |           | Min.        | Typ.  | Max.  |      |                                  |
| Standby Circuit Current                            | ISTB      | -           | 0     | 10    | μA   | VEN/SYNC=0V                      |
| Circuit Current                                    | IQ        | -           | 4.2   | 6.5   | mA   | IO=0A,RT=51kΩ,VINV=0.7V          |
| 【SW Block】   |           |             |       |       |      |                                  |
| POWER MOS FET ON Resistance                        | RON       | -           | 0.24  | 0.5   | Ω    | ISW=50mA                         |
| Operating Output Current Of Overcurrent Protection | IOLIMIT   | 4           | 7     | -     | A    |                                  |
| Output Leak Current                                | IOLLEAK   | -           | 0     | 30    | μA   | VIN=35V, VEN/SYNC=0V             |
| 【Error Amp Block】                                  |           |             |       |       |      |                                  |
| Reference Voltage 1                                | VREF1     | 0.784       | 0.800 | 0.816 | V    | VFB=VINV                         |
| Reference Voltage 2                                | VREF2     | 0.780       | 0.800 | 0.820 | V    | VIN=10~16V,VFB=VINV              |
| Reference Voltage Input Regulation                 | ΔVREF     | -           | 0.5   | -     | %    |                                  |
| Input Bias Current                                 | IB        | -1          | -     | -     | μA   | VINV=0.6V                        |
| Maximum FB Voltage                                 | VFBH      | 2.2         | 2.4   | -     | V    | VINV=0V                          |
| Minimum FB Voltage                                 | VFBL      | -           | 0.5   | 0.6   | V    | VINV=2V                          |
| FB Sink Current                                    | IFBSINK   | -0.47       | -1.16 | -2.45 | mA   | VFB=1V,VINV=1V                   |
| FB Source Current                                  | IFBSOURCE | 1           | 5     | 15    | mA   | VFB=1V,VINV=0.6V                 |
| Soft Start Time                                    | TSS       | 3           | 5     | 9     | mS   | Ta=-40~105°C                     |
| 【Oscillator Block】                                 |           |             |       |       |      |                                  |
| Oscillation Frequency                              | FOSC      | 285         | 300   | 315   | kHz  | VIN=7V,RT=51kΩ                   |
| Frequency Input Regulation                         | ΔFOSC     | -           | 0.5   | -     | %    | VIN=7~16V                        |
| 【Enable/Sync Input Block】                          |           |             |       |       |      |                                  |
| Output ON Voltage                                  | VENON     | 2.6         | -     | -     | V    | VEN/SYNC Sweep Up,Ta=-40~105°C   |
| Output OFF Voltage                                 | VENOFF    | -           | -     | 0.8   | V    | VEN/SYNC Sweep Down,Ta=-40~105°C |
| Sink Current                                       | IEN/SYNC  | -           | 35    | 90    | μA   |                                  |
| External Sync Frequency                            | FSYNC     | 495         | 500   | 505   | kHz  | RT=51kΩ,EN/SYNC=500kHz,Duty 50%  |

\* Not designed to be radiation resistant.

●Reference Data

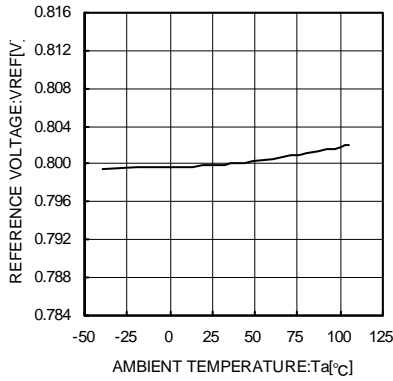


Fig.1 Output reference voltage vs. Ambient temperature (All series)

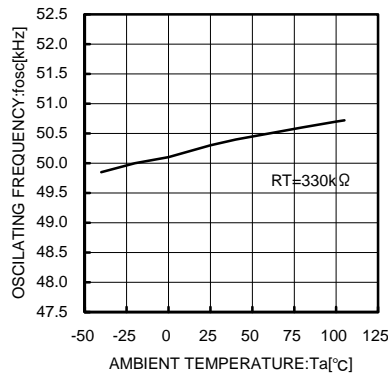


Fig.2 Frequency vs. Ambient temperature (All series)

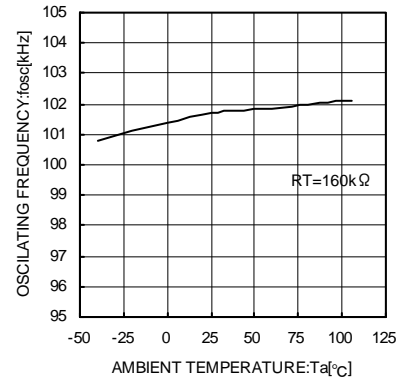


Fig.3 Frequency vs. Ambient temperature (All series)

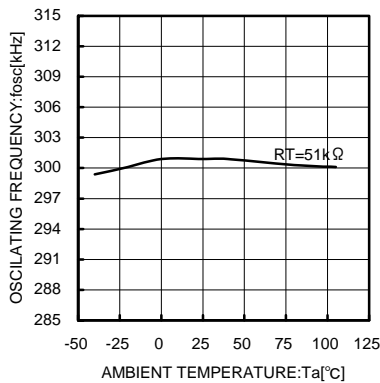


Fig.4 Frequency vs. Ambient temperature (All series)

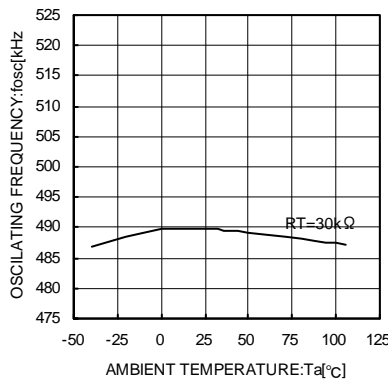


Fig.5 Frequency vs. Ambient temperature (All series)

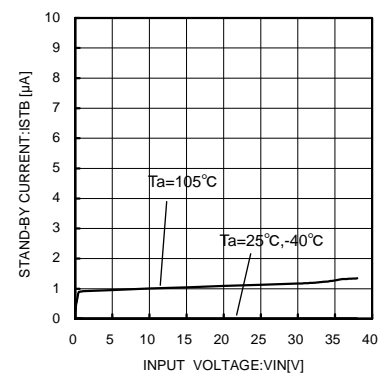


Fig.6 Standby Current (BD9006F/HFP, BD9007F/HFP)

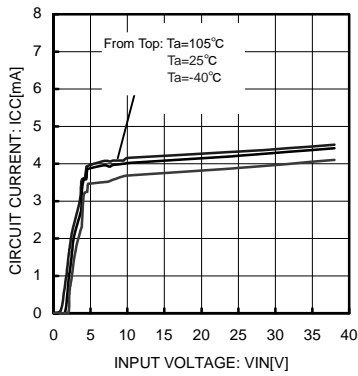


Fig.7 Circuit Current (BD9006F/HFP, BD9007F/HFP)

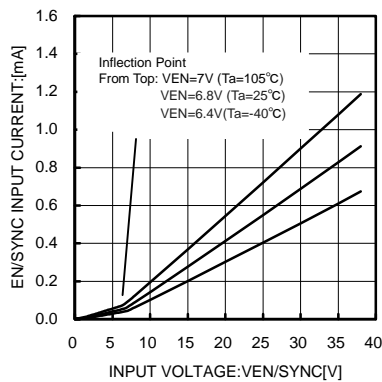


Fig.8 EN/SYNC Input Current (All series)

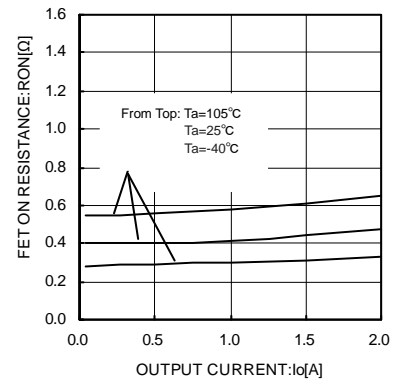


Fig.9 ON Resistance VIN=7V (BD9006F/HFP, BD9007F/HFP)

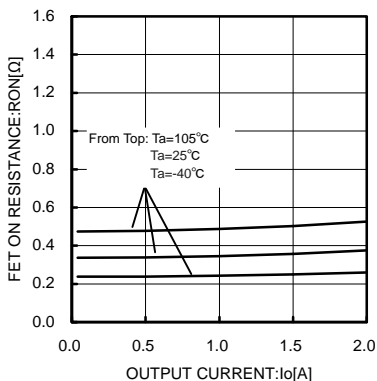


Fig.10 ON Resistance VIN=13.2V (BD9006F/HFP, BD9007F/HFP)

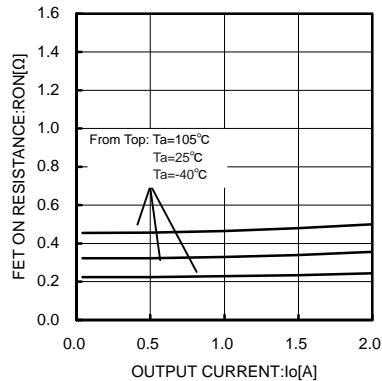


Fig.11 ON Resistance VIN=35V (BD9006F/HFP, BD9007F/HFP)

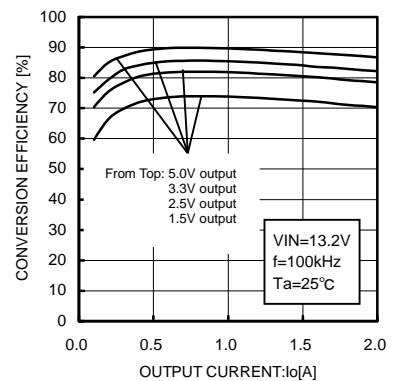


Fig.12 Efficiency f=100kHz (BD9006F/HFP, BD9007F/HFP)

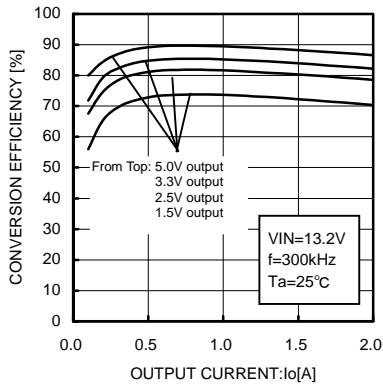


Fig.13 Efficiency f=300kHz (BD9006F/HFP, BD9007F/HFP)

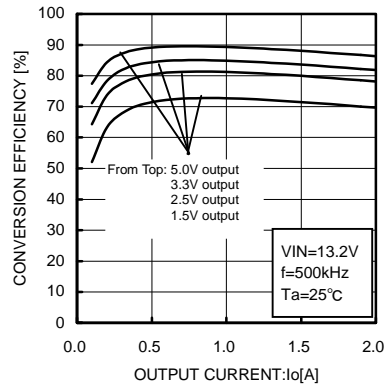


Fig.14 Efficiency f=500kHz (BD9006F/HFP, BD9007F/HFP)

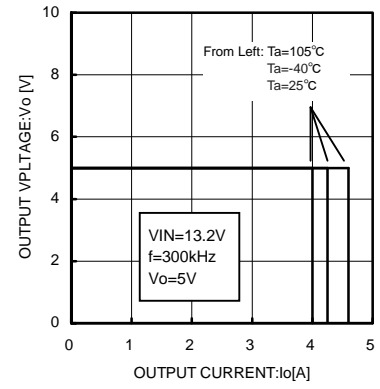


Fig.15 Over-current Protection Operation Current (BD9006F/HFP, BD9007F/HFP)

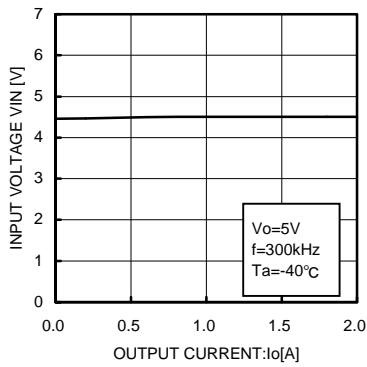


Fig.16 The lowest voltage of possible operation Ta=-40°C (BD9006F/HFP, BD9007F/HFP)

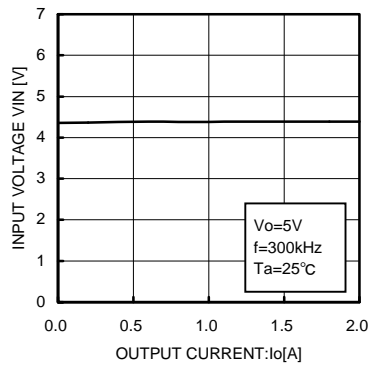


Fig.17 The lowest voltage of possible operation Ta=25°C (BD9006F/HFP, BD9007F/HFP)

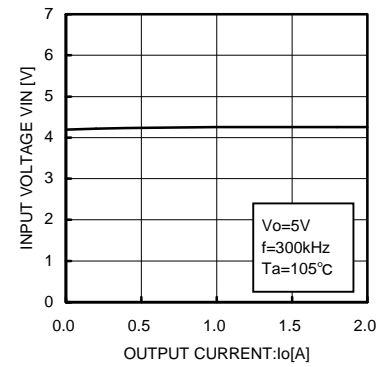


Fig.18 The lowest voltage of possible operation Ta=105°C (BD9006F/HFP, BD9007F/HFP)

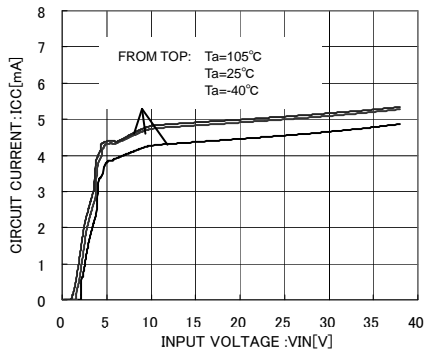


Fig.19 Circuit Current (BD9009HFP)

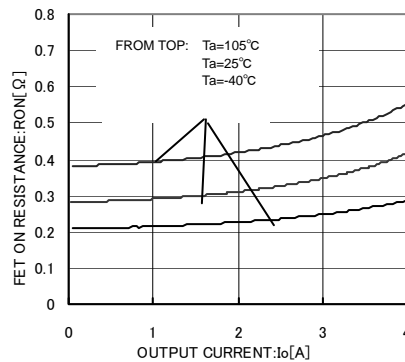


Fig.20 ON Resistance VIN=7V (BD9009HFP)

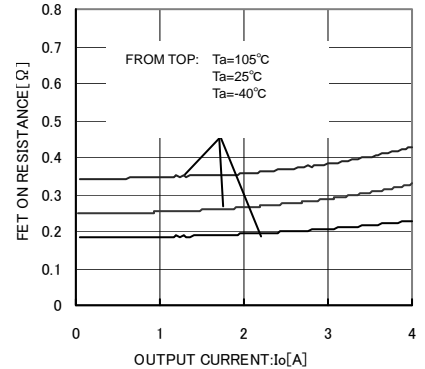


Fig.21 ON Resistance VIN=13.2V (BD9009HFP)

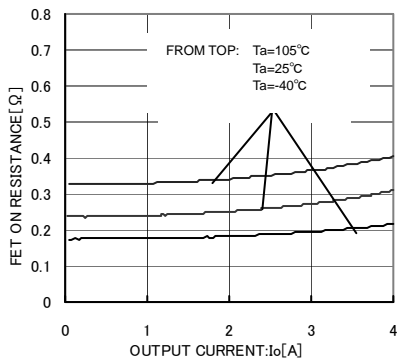


Fig.22 ON Resistance VIN=35V (BD9009HFP)

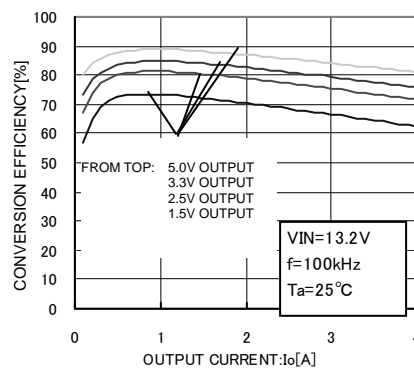


Fig.23 Efficiency f=100kHz (BD9009HFP)

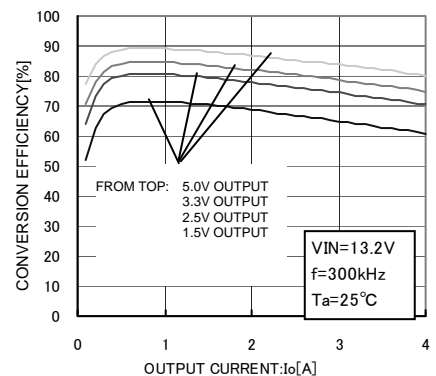


Fig.24 Efficiency f=300kHz (BD9009HFP)

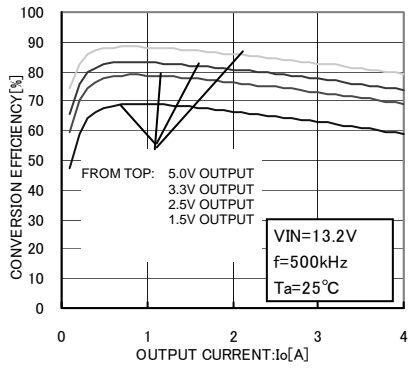


Fig.25 Efficiency f=500kHz (BD9009HFP)

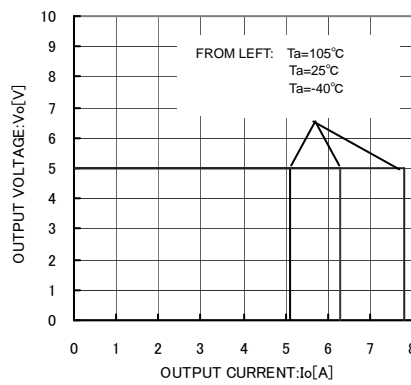


Fig.26 Over-current Protection Operation Current (BD9009HFP)

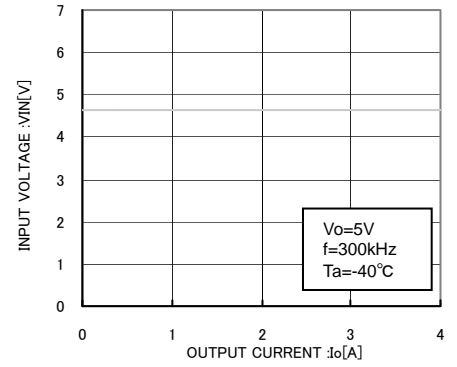


Fig.27 The lowest voltage of possible operation Ta=-40°C (BD9009HFP)

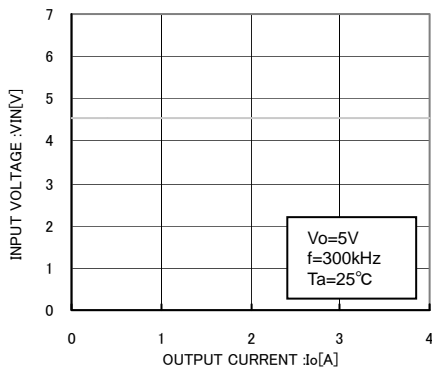


Fig.28 The lowest voltage of possible operation Ta=25°C (BD9009HFP)

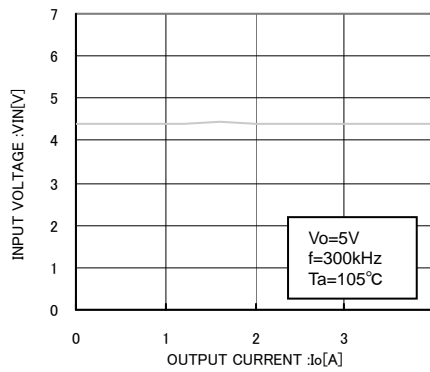


Fig.29 The lowest voltage of possible operation Ta=105°C (BD9009HFP)

●Block Diagrams / Application circuit / PIN assignment

(BD9006F/BD9007F)

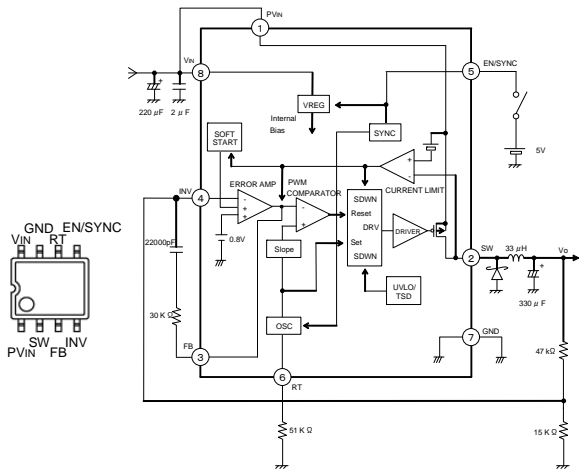


Fig.30

| No. | Pin name | Function                              |
|-----|----------|---------------------------------------|
| 1   | PVIN     | Power system power supply input       |
| 2   | SW       | Output                                |
| 3   | FB       | Error Amp output                      |
| 4   | INV      | Output voltage feedback               |
| 5   | EN/SYNC  | Enable/Synchronizing pulse input      |
| 6   | RT       | Frequency setting resistor connection |
| 7   | GND      | Ground                                |
| 8   | VIN      | Power supply input                    |

\* VIN and PVIN must be shorted before use

(BD9006HFP/BD9007HFP)

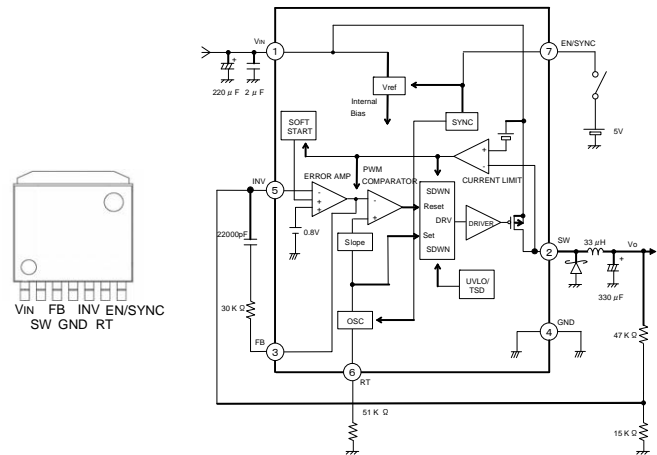


Fig.31

| No. | Pin name | Function                              |
|-----|----------|---------------------------------------|
| 1   | VIN      | Power supply input                    |
| 2   | SW       | Output                                |
| 3   | FB       | Error Amp output                      |
| 4   | GND      | Ground                                |
| 5   | INV      | Output voltage feedback               |
| 6   | RT       | Frequency setting resistor connection |
| 7   | EN/SYNC  | Enable/Synchronizing pulse input      |
| FIN | -        | Ground                                |

(BD9009HFP)

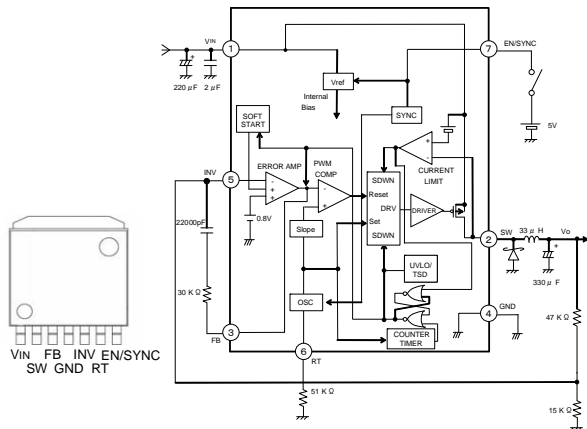


Fig.32

| No. | Pin name | Function                              |
|-----|----------|---------------------------------------|
| 1   | VIN      | Power supply input                    |
| 2   | SW       | Output                                |
| 3   | FB       | Error Amp output                      |
| 4   | GND      | Ground                                |
| 5   | INV      | Output voltage feedback               |
| 6   | RT       | Frequency setting resistor connection |
| 7   | EN/SYNC  | Enable/Synchronizing pulse input      |
| FIN | -        | Ground                                |

## ●Description of operations

### • ERROR AMP

The ERROR AMP block is an error amplifier used to input the reference voltage (0.8V Typ.) and the INV pin voltage. The output FB pin controls the switching duty and output voltage  $V_o$ . These INV and FB pins are externally mounted to facilitate phase compensation. Inserting a capacitor and resistor between these pins enables adjustment of phase margin. (Refer to recommended examples on pages 13~15.)

### • SOFT START

The SOFT START block provides a function to prevent the overshoot of the output voltage  $V_o$  through gradually increasing the normal rotation input of the error amplifier when power supply turns ON to gradually increase the switching Duty. The soft start time is set to 5msec (Typ.).

### • SYNC

By making the "EN/SYNC" terminal less than 0.8V, the circuit can be shut down.

Furthermore, by applying pulse with higher frequency than the configured oscillation frequency to the "EN/SYNC" terminal, external sync is possible. (Sync possible with double the configured frequency-configured frequency or 500kHz)

### • OSC(Oscillator)

This circuit generates the pulse wave to be input to the slope, and by connecting resistance to "RT", 50~500kHz oscillating frequency can be configured. (Refer to p.13 Fig.40)

### • slope

This block generates saw tooth waves from the clock generated by the OSC. The generated saw tooth waves are sent to PWM COMPARATOR.

### • PWM COMPARATOR

The PWM COMPARATOR block is a comparator to make comparison between the FB pin and internal saw tooth wave and output a switching pulse.

The switching pulse duty varies with the FB value.

min Duty width : 250ns(BD9006F/HFP,BD9007HFP)

min Duty width : 360ns(BD9009HFP)

### • TSD (Thermal Shut Down)

In order to prevent thermal destruction/thermal runaway of the IC, the TSD block will turn OFF the output when the chip temperature reaches approximately 150°C or more. When the chip temperature falls to a specified level, the output will be reset. However, since the TSD is designed to protect the IC, the chip junction temperature should be provided with the thermal shutdown detection temperature of less than approximately 150°C.

### • CURRENT LIMIT

While the output POWER P-ch MOS FET is ON, if the voltage between drain and source (ON resistance  $\times$  load current) exceeds the reference voltage internally set with the IC, this block will turn OFF the output to latch. The overcurrent protection detection values have been set as shown below:

BD9009/HFP . . . 7A (Typ.)

BD9006F/HFP, BD9007F/HFP . . . 4A (Typ.)

Furthermore, since BD9006F/HFP,BD9007F/HFP overcurrent protection is an automatically reset, after the output is turned OFF and latched, the latch will be reset with the RESET signal output by each oscillation frequency.

When BD9009HFP over current protection circuit operates, output is turned off immediately, and then this IC restart to operate after 4096/fosc sec.

However, this protection circuit is only effective in preventing destruction from sudden accident. It does not support for the continuous operation of the protection circuit (e.g. if a load, which significantly exceeds the output current capacitance, is normally connected). Furthermore, since the overcurrent protection detection value has negative temperature characteristics, consider thermal design.



● Timing Chart

(All series)

• Basic Operation

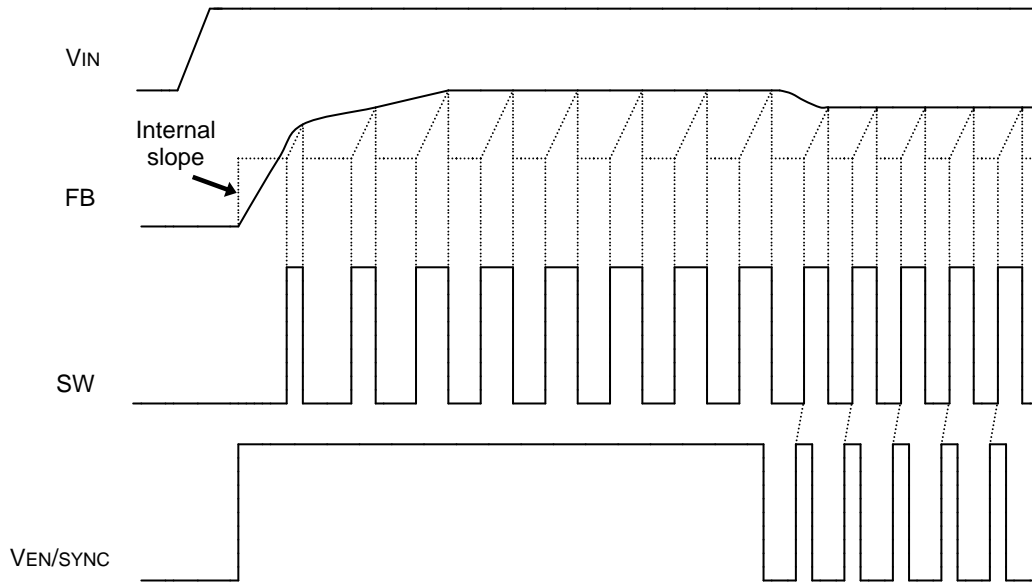


Fig.33

• Over Current Protection Operation

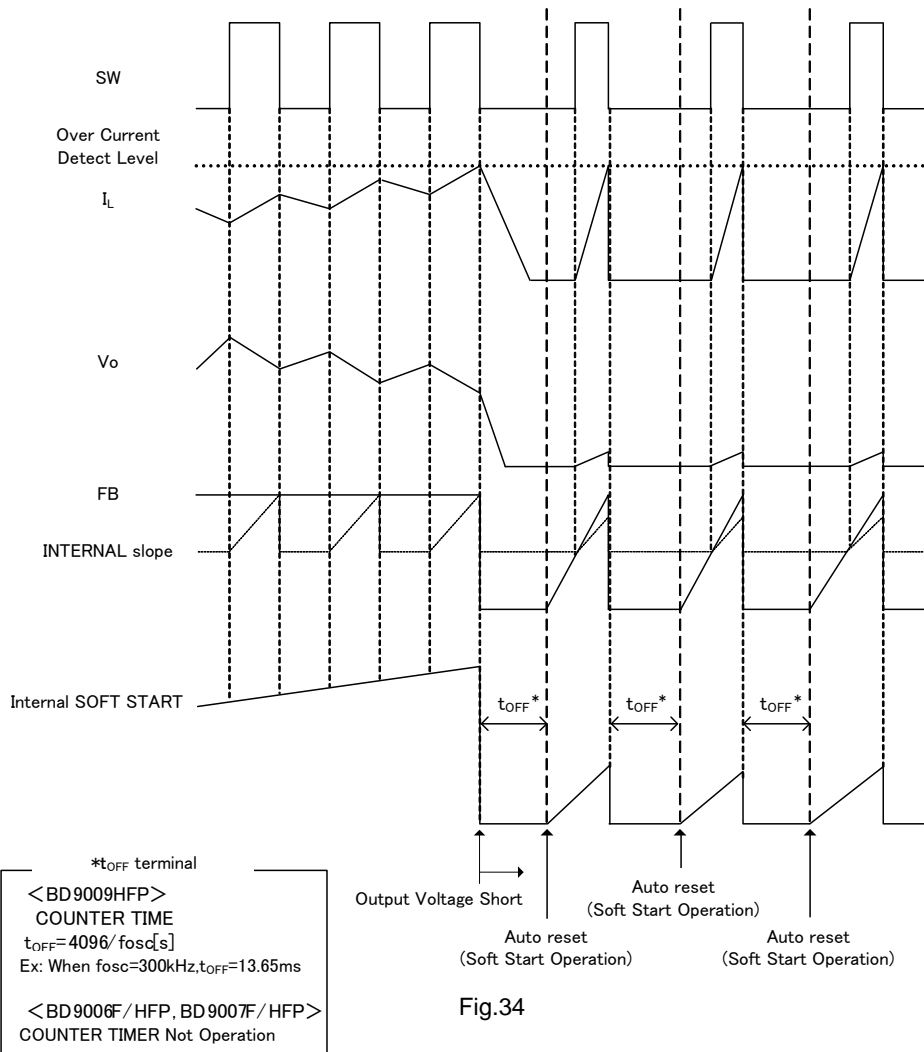


Fig.34

●External synchronizing function

In order to activate the external synchronizing function, connect the frequency setting resistor to the RT pin and then input a synchronizing signal to the EN/SYNC pin. As the synchronizing signal, input a pulse wave higher than a frequency determined with the setting resistor (RT).

However, the external sync frequency should be configured at less than double the configured frequency.

(ex.) When the configured frequency is 100kHz, the external sync frequency should be less than 200kHz.

Furthermore, the pulse wave's LOW voltage should be under 0.8V and the HIGH voltage over 2.6V (when the HIGH voltage is over 6V the EN/SYNC input current increases [see p.4 Fig.8]), the through rate of stand-up (and stand-down) under 20V/ $\mu$ S.

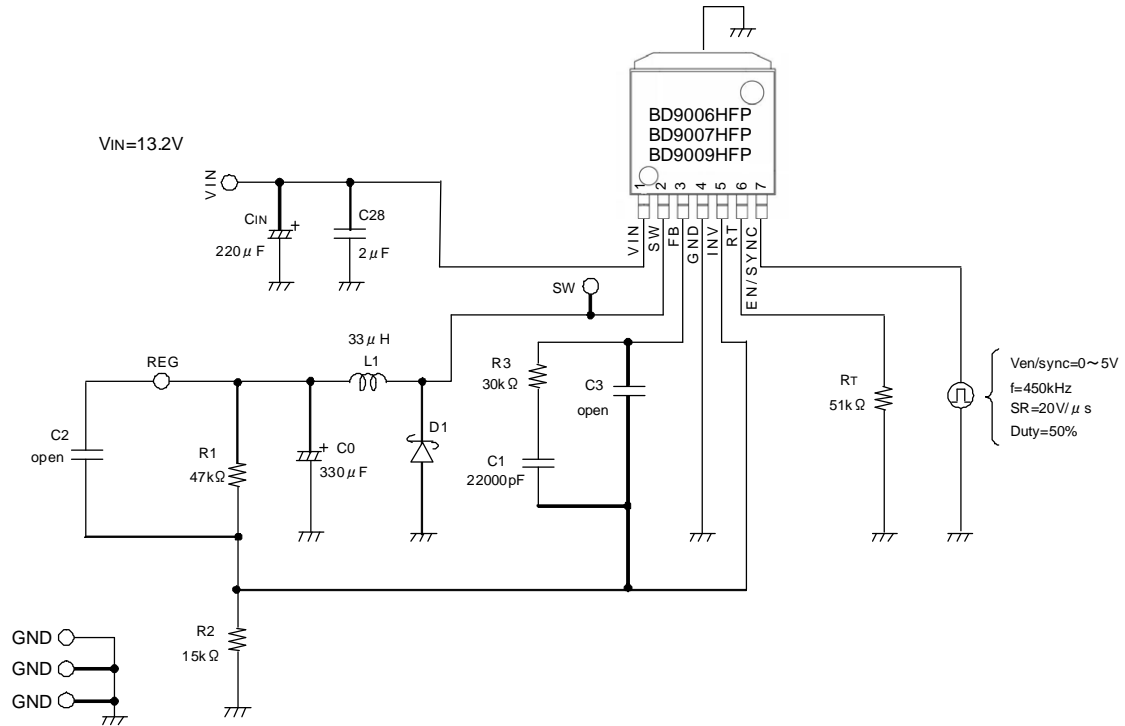


Fig.35 External Sync Sample Circuit  
(Vo=3.3V, Io=1A, f=300kHz, EN/SYNC=450kHz)

●Description of external components

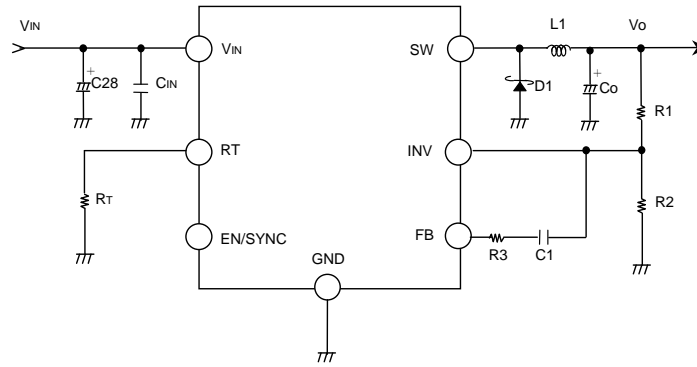


Fig.36

| Design Procedure   | Sample Calculations   |
|--|---|
| <p><math>V_o</math>=Output voltage, <math>V_{IN}</math> (Max.)=Maximum input voltage<br/> <math>I_o</math> (Max.)=Maximum load current, <math>f</math>=Oscillation frequency</p>   | <p>When <math>V_o=3.3V</math>, <math>V_{IN}</math> (Typ.)=13.2V<br/> <math>I_o</math>(Max.)=1A and <math>f=300kHz</math></p>  |
| <p>1. Setting or output voltage<br/>                     Output voltage can be obtained by the formula shown below:</p> $V_o=0.8 \times (1+R1/R2)$ <p>Use the formula to select the R1 and R2.<br/>                     Furthermore, set the R2 to 30kΩ or less.<br/>                     Select the current passing through the R1 and R2 to be small enough for the output current.</p>  | <p>When <math>V_o=3.3V</math> and <math>R2=15k\Omega</math></p> $3.3=0.8 \times (1+R1/15k\Omega)$ $R1=46.875k\Omega \approx 47k\Omega$ <p style="text-align: right;"><u><math>R1=47k\Omega</math></u></p>   |
| <p>2. Selection of coil (L1)<br/>                     The value of the coil can be obtained by the formula shown below:</p> $L1=(V_{IN}-V_o) \times V_o / (V_{IN} \times f \times \Delta I_o)$ <p><math>\Delta I_o</math>: Output ripple current<br/> <math>\Delta I_o</math> should typically be approximately 20 to 30% of <math>I_o</math>.</p> <p>If this coil is not set to the optimum value, normal (continuous) Oscillation may not be achieved. Furthermore, set the value of the coil with an adequate margin so that the peak current passing through the coil will not exceed the rated current of the coil.</p>   | <p>When <math>V_{IN}=13.2V</math>, <math>V_o=3.3V</math>, <math>I_o=1A</math> and <math>f=300kHz</math>,</p> $L1=(13.2-3.3) \times 3.3 / \{13.2 \times 300k \times (1 \times 0.3)\}$ $=27.5\mu H \approx 33\mu H$ <p style="text-align: right;"><u><math>L1=33\mu H</math></u></p>  |
| <p>3. Selection of output capacitor (Co)<br/>                     The output capacitor can be determined according to the output ripple voltage <math>\Delta V_o</math>(p-p) required. Obtain the required ESR value by the formula shown below and then select the capacitance.</p> $\Delta I_L=(V_{IN}-V_o) \times V_o / (L \times f \times V_{IN})$ $\Delta V_{pp}=\Delta I_L \times ESR+(\Delta I_L \times V_o) / (2 \times C_o \times f \times V_{IN})$ <p>Set the rating of the capacitor with an adequate margin to the output voltage. Also, set the maximum allowable ripple current with an adequate margin to <math>\Delta I_L</math>. Furthermore, the output rise time should be shorter than the soft start time. Select the output capacitor having a value smaller than that obtained by the formula shown below.</p> $C_{MAX} = \frac{3.0m \times (I_{LIMIT}-I_o(Max))}{V_o}$ <p><math>I_{LIMIT}</math> : 2A (BD9006F/HFP, BD9007F/HFP),4A (BD9009HFP)<br/>                     If this capacitances is not optimum, faulty startup may result.</p> <p>(※3.0m is soft start time(min).)</p> | <p><math>V_{IN}=13.2V</math>, <math>V_o=3.3V</math>, <math>L=33\mu H</math>, <math>f=300kHz</math></p> $\Delta I_L=(13.2-3.3) \times 3.3 / (33 \times 10^{-6} \times 300 \times 10^3 \times 13.2)$ $=0.25$ <p style="text-align: right;"><u><math>\Delta I_L=0.25A</math></u></p> <p>When <math>I_{LIMIT}</math>: 2A, <math>I_o</math>(Max)=1A, <math>V_o=3.3V</math></p> $C_{MAX} = 3.0m \times (2-1) / 3.3$ $\approx 910\mu$ <p style="text-align: right;"><u><math>C_{MAX}=910\mu F</math></u></p> |

| Design Method  | Sample Calculations   |
|--|---|
| <p>4. Selection of diode (D1)<br/>Set diode rating with an adequate margin to the maximum load current. Also, make setting of the rated inverse voltage with an adequate margin to the maximum input voltage.</p> <p>A diode with a low forward voltage and short reverse recovery time will provide high efficiency.</p>  | <p>When<br/><math>V_{IN(max.)}=35V</math><br/><math>I_{o(max.)}=2A</math></p> <p>Diode ratings must include:<br/>Current over 2A<br/>Withstand minimum 35V</p>  |
| <p>5. Selection of input capacitor (C<sub>IN</sub>, C28)<br/>Two capacitors, ceramic capacitor C<sub>IN</sub> and bypass capacitor C28 should be inserted between the V<sub>IN</sub> and GND. Be sure to insert a ceramic capacitor of 2 to 10<math>\mu</math>F for the C<sub>IN</sub>. The capacitor C28 should have a low ESR and a significantly large ripple current. The ripple current I<sub>RMS</sub> can be obtained by the following formula:</p> $I_{RMS}=I_o \times \sqrt{V_o \times (V_{IN}-V_o)/V_{IN}^2}$ <p>Select capacitors that can accept this ripple current. If the capacitance of C<sub>IN</sub> and C28 is not optimum, the IC may malfunction.</p> | <p>When <math>V_{IN}=13.2V</math>, <math>V_o=3.3V</math> and <math>I_o=1A</math>:</p> $I_{RMS}=1 \times \sqrt{3.3 \times (13.2-3.3)/(13.2)^2}$ <p style="text-align: right;"><u><math>I_{RMS}=0.433A</math></u></p> |
| <p>6. Setting of oscillating frequency<br/>Referring Fig.40 on the following page, select R for the oscillating frequency to be used.</p>  | <p>When <math>f=300kHz</math><br/>From p.13 Fig.40, a resistance of <math>R_T=51k\Omega</math> is selected.<br/><u><math>R_T=51k\Omega</math></u></p>   |
| <p>7. Setting of phase compensation (R3 and C1)<br/>The phase margin can be set through inserting a capacitor or a capacitor and resistor between the INV pin and the FB pin. Each set value varies with the output coil, capacitance, I/O voltage, and load. Therefore, set the phase compensation to the optimum value according to these conditions. (For details, refer to Application circuit on page.13~)<br/>If this setting is not optimum, output oscillation may result.</p>   | <p>※Please contact us if there are any questions regarding phase compensation configuration.</p>  |

※The set values listed above are all reference values. On the actual mounting of the IC, the characteristics may vary with the routing of wirings and the types of parts in use. In the connection, it is recommended to thoroughly verify these values on the actual system prior to use.

#### ●Directions for pattern layout of PCB

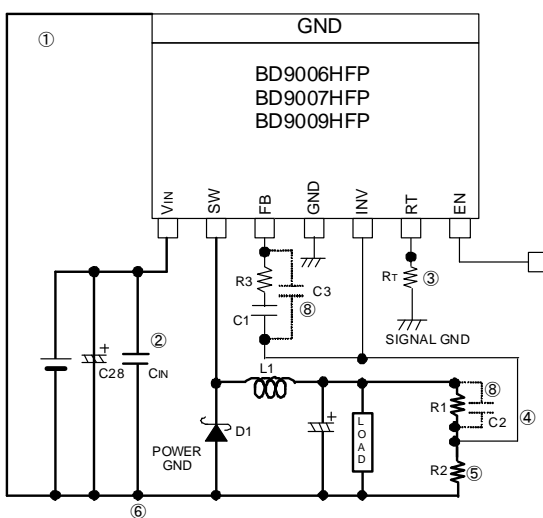


Fig.37

- ① Arrange the wirings shown by heavy lines as short as possible in a broad pattern.
- ② Locate the input ceramic capacitor C<sub>IN</sub> as close to the V<sub>IN</sub>-GND pin as possible.
- ③ Locate the R<sub>T</sub> as close to the GND pin as possible.
- ④ Locate the R<sub>1</sub> and R<sub>2</sub> as close to the INV pin as possible, and provide the shortest wiring from the R<sub>1</sub> and R<sub>2</sub> to the INV pin.
- ⑤ Locate the R<sub>1</sub> and R<sub>2</sub> as far away from the L<sub>1</sub> as possible.
- ⑥ Separate POWER GND (Schottky diode, I/O capacitor's GND) and SIGNAL GND (R<sub>T</sub>, GND), so that SW noise doesn't have an effect on SIGNAL GND at all.
- ⑦ Design the POWER wire line as wide and short as possible.
- ⑧ Additional pattern for C<sub>2</sub> and C<sub>3</sub> expand compensation flexibility.

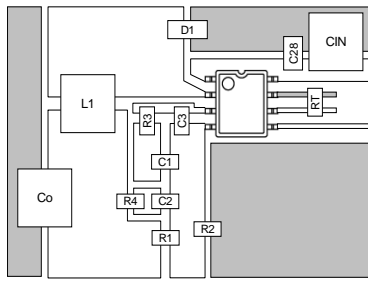


Fig.38 BD9006F, BD9007F Reference Layout Pattern

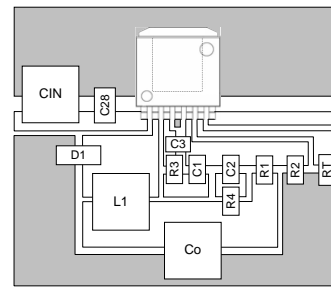


Fig.39 BD9006HFP, BD9007HFP, BD9009HFP Reference Layout Pattern

※As shown above, design the GND pattern as large as possible within inner layer.  
 ※Gray zones indicate GND.

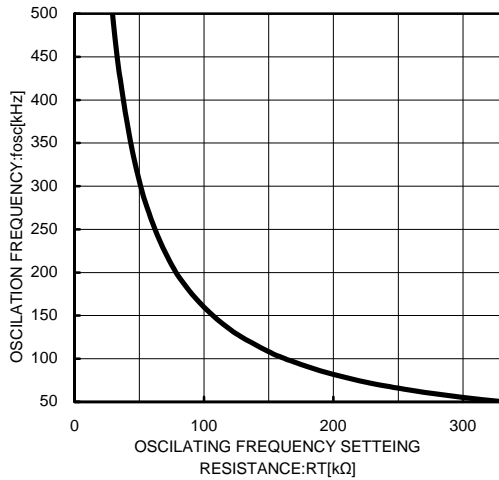


Fig.40 RT Resistance Values vs. Oscillating Frequency

| RT[kΩ] | fosc[kHz] | RT[kΩ] | fosc[kHz] |
|--------|-----------|--------|-----------|
| 27     | 537       | 100    | 160       |
| 30     | 489       | 110    | 146       |
| 33     | 449       | 120    | 134       |
| 36     | 415       | 130    | 124       |
| 39     | 386       | 150    | 108       |
| 43     | 353       | 160    | 102       |
| 47     | 324       | 180    | 91        |
| 51     | 300       | 200    | 82        |
| 56     | 275       | 220    | 75        |
| 62     | 250       | 240    | 69        |
| 68     | 229       | 270    | 61        |
| 75     | 209       | 300    | 55        |
| 82     | 192       | 330    | 50        |
| 91     | 174       | 360    | 46        |

※The values in the graph for oscillating frequency are Typical values, and variance of ±5% for BD9006F/HFP, BD9009HFP and ±20% for BD9007F/HFP should be considered.

●Phase Compensation setting procedure

1. Application stability conditions

The following section describes the stability conditions of the negative feedback system.

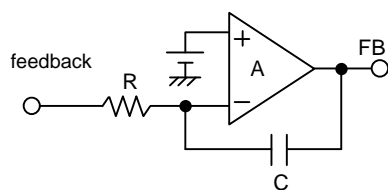
Since the DC/DC converter application is sampled according to the switching frequency, GBW (frequency at 0-dB gain) of the overall system should be set to 1/10 or less of the switching frequency. The following section summarizes the targeted characteristics of this application.

- At a 1 (0-dB) gain, the phase delay is 150° or less (i.e. the phase margin is 30° or more).
- The GBW for this occasion is 1/10 or less of the switching frequency.

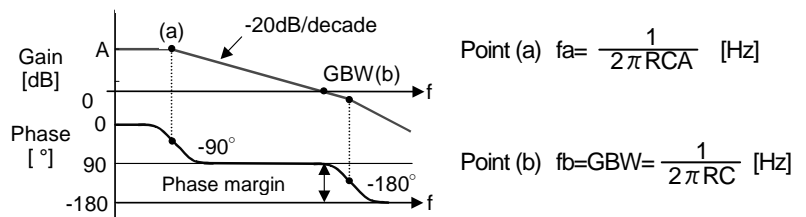
Responsiveness is determined with restrictions on the GBW. To improve responsiveness, higher switching frequency should be provided.

Replace a secondary phase delay (-180°) with a secondary phase lead by inserting two-phase leads, to ensure the stability through the phase compensation. Furthermore, the GBW (i.e., frequency at 0-dB gain) is determined according to phase compensation capacitance provided for the error amplifier. Consequently, in order to reduce the GBW, increase the capacitance value.

(1) Typical integrator (low pass filter)



(2) Open loop characteristics of integrator

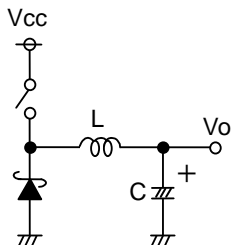


Since the error amplifier is provided with (1) or (2) phase compensation, the low pass filter is applied. In the case of the DC/DC converter application, the R becomes a parallel resistance of the feedback resistance.

2. For output capacitors having high ESR, such as electrolyte capacitor

For output capacitors that have high ESR (i.e., several Ω), the phase compensation setting procedure becomes comparatively simple. Since the DC/DC converter application has a LC resonant circuit attached to the output, a -180° phase-delay occurs in that area. If ESR component is present, however a +90° phase-lead occurs to shift the phase delay to -90°. Since the phase delay should be set within 150°, it is a very effective method but tends to increase the ripple component of the output voltage.

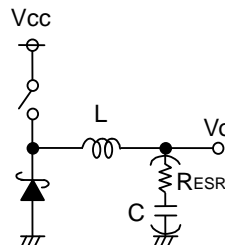
(1) LC resonant circuit



$$f_r = \frac{1}{2\pi\sqrt{LC}} \text{ [Hz]}$$

At this resonance point, a -180° phase-delay occurs.

(2) With ESR provided



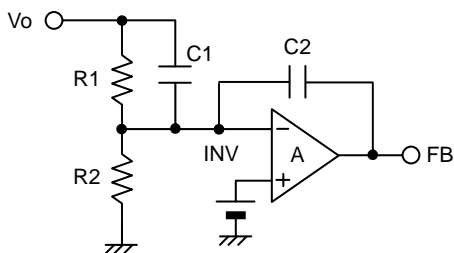
$$f_r = \frac{1}{2\pi\sqrt{LC}} \text{ [Hz]: Resonance}$$

$$f_{ESR} = \frac{1}{2\pi R_{ESR}C} \text{ [Hz]: Phase lead}$$

A -90° phase-delay occurs.

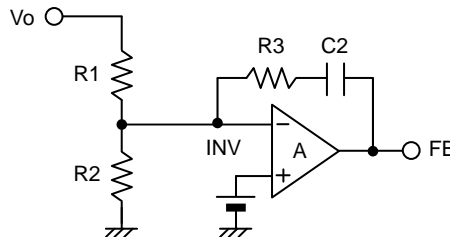
According to changes in phase characteristics, due to the ESR, only one phase lead should be inserted. For this phase lead, select either of the methods shows below:

(3) Insert Feedback Resistance in the C.



$$\text{Phase lead } f_z = \frac{1}{2\pi C1R1} \text{ [Hz]}$$

(4) Insert the R3 in integrator.



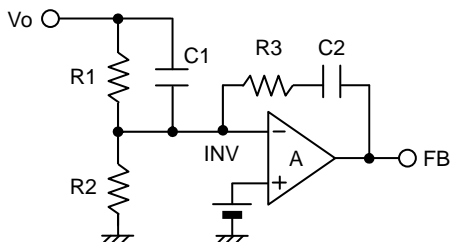
$$\text{Phase lead } f_z = \frac{1}{2\pi C2R3} \text{ [Hz]}$$

To cancel the LC resonance, the frequency to insert the phase lead should be set close to the LC resonant frequency. The setting above have is estimated. Consequently, the setting may be adjusted on the actual system. Furthermore, since these characteristics vary with the layout of PCB loading conditions, precise calculations should be made on the actual system.

3. For output capacitors having low ESR, such as low impedance electrolyte capacitor or OS-CON

In order to use capacitors with low ESR (i.e., several tens of mΩ), two phase-leads should be inserted so that a -180° phase-delay, due to LC resonance, will be compensated. The following section shows a typical phase compensation procedure.

(1) Phase compensation with secondary phase lead



$$\text{Phase lead : } f_{z1} = \frac{1}{2\pi R1C1} \text{ [Hz]}$$

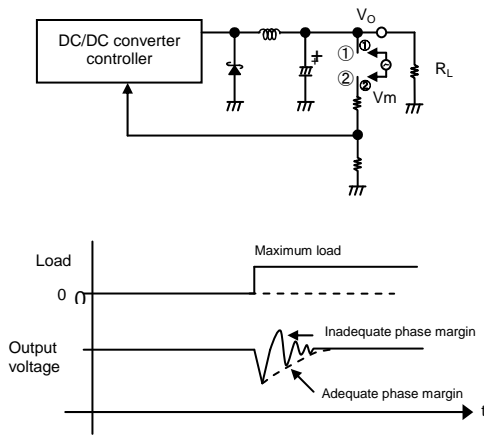
$$\text{Phase lead : } f_{z2} = \frac{1}{2\pi R3C2} \text{ [Hz]}$$

$$\text{LC resonant : } f_r = \frac{1}{2\pi\sqrt{LC}} \text{ [Hz]}$$

To set phase lead frequency, insert both of the phase leads close to the LC resonant frequency. According to empirical rule, setting the phase lead frequency fZ2 with R3 and C2 lower than the LC resonant frequency fr, and the phase lead frequency fZ1 with the R1 and C1 higher than the LC resonant frequency fr, will provide stable application conditions.

<Reference> Measurement of open loop of the DC/DC converter

To measure the open loop of the DC/DC converter, use the gain phase analyzer or FRA to measure the frequency characteristics.



<Procedure>

1. Check to ensure output causes no oscillation at the maximum load in closed loop.
2. Isolate ① and ② and insert \$V\_m\$ (with amplitude of approximately 100mVpp).
3. Measure (probe) the oscillation of ① to that of ②.

Furthermore, the phase margin can also be measured with the load responsiveness. Measure variations in the output voltage when instantaneously changing the load from no load to the maximum load. Even though ringing phenomenon is caused, due to low phase margin, no ringing takes place. Phase margin is provided. However, no specific phase margin can be probed.

※Please contact us if you have any questions regarding phase compensation.

●Heat Loss

For thermal design, be sure to operate the IC within the following conditions.

(Since the temperatures described hereunder are all guaranteed temperature, take margin into account.)

1. The ambient temperature \$T\_a\$ is to be 105°C or less.
2. The chip junction temperature \$T\_j\$ is to be 150°C or less.

The chip junction temperature \$T\_j\$ can be considered in the following two patterns:

To obtain \$T\_j\$ from the IC surface temperature \$T\_c\$ in actual use state,  
 $T_j = T_c + \theta_j - c \times W$

< Reference value >  $\theta_j - c$  : HRP7 7°C/W  
 SOP8 32.5°C/W

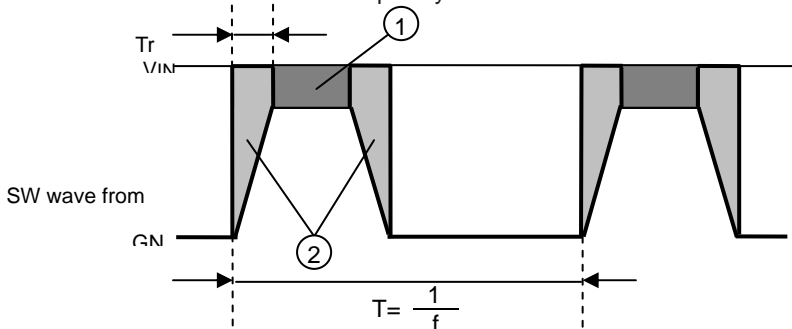
To obtain \$T\_j\$ from the ambient temperature \$T\_a\$  
 $T_j = T_a + \theta_j - a \times W$

< Reference. value >  $\theta_j - a$  : HRP7 89.3°C/W Single piece of IC  
 54.3°C/W 2-layer PCB (Copper foil area on the front side of PCB: 15×15mm<sup>2</sup>)  
 22.7°C/W 2-layer PCB (Copper foil area on the front side of PCB: 70×70mm<sup>2</sup>)  
 PCB size: 70×70×1.6mm<sup>3</sup>  
 (PCB incorporates thermal via.)  
 Copper foil area on the front side of PCB: 10.5×10.5mm<sup>2</sup>  
 SOP8 222.2°C/W Single piece of IC  
 181.8°C/W 1-layer PCB  
 PCB size: 70×70×1.6mm<sup>3</sup>

The heat loss \$W\$ of the IC can be obtained by the formula shown below:

$$W = R_{on} \times I_o^2 \times \frac{V_o}{V_{IN}} + V_{IN} \times I_{CC} + T_r \times V_{IN} \times I_o \times f$$

\$R\_{on}\$: ON resistance of IC (refer to page.4,5) \$I\_o\$: Load current  
 \$V\_o\$: Output voltage \$V\_{IN}\$: Input voltage \$I\_{CC}\$: Circuit current (refer to page.2,3)  
 \$T\_r\$: Switching rise/fall time (approximately 20nsec)  
 \$f\$: Oscillation frequency



$$\text{① } R_{on} \times I_o^2$$

$$\text{② } 2 \times \frac{1}{2} \times T_r \times \frac{1}{T} \times V_{IN} \times I_o$$

$$= T_r \times V_{IN} \times I_o \times f$$

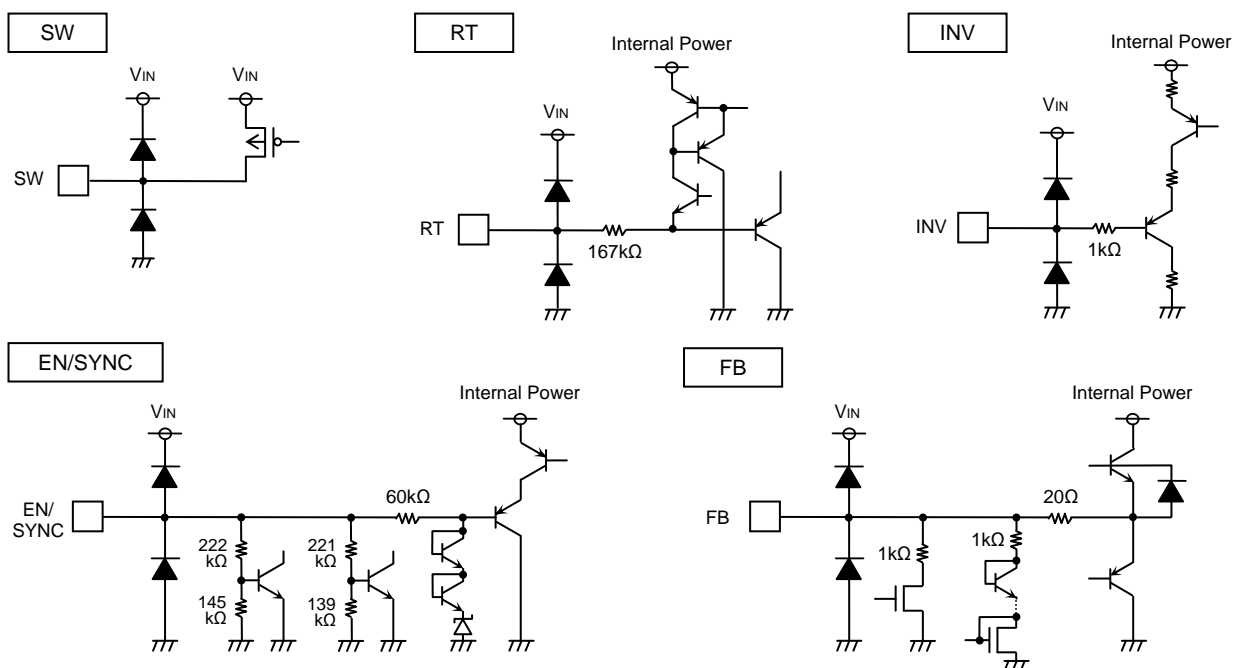


Fig.41 Equivalent circuit

●Cautions on use

1. Absolute maximum ratings

If excess in the absolute maximum ratings, such as supply voltage, temperature range of operating conditions, etc., can break down the devices, thus making impossible to identify breaking mode, such as a short circuit or an open circuit. If any over rated values will expect to exceed the absolute maximum ratings, consider adding circuit protection devices, such as fuses.

2. GND potential

Ground-GND potential should maintain at the minimum ground voltage level. Furthermore, no terminals should be lower than the GND potential voltage including electric transients.

3. Thermal design

Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions.

4. Inter-pin shorts and mounting errors

When attaching to the set substrate, pay special attention to the direction and proper placement of the IC. If the IC is attached incorrectly, it may be destroyed.

Furthermore, when using the IC with VIN and EN/SYNC terminals shorted, and the 5-pin (SOP8 package) or 7-pin (HRP7 package) EN/SYNC terminal and 6-pin RT terminal are shorted, the IC may also be damaged when VIN>7V.

5. Operation in strong electromagnetic field

Use caution when using the IC in the presence of a strong electromagnetic field as doing so may cause the IC to malfunction.

6. Inspection with set printed circuit board

When testing the IC on an application board, connecting a capacitor to a pin with low impedance subjects the IC to stress. Always discharge capacitors after each process or step. Always turn the IC's power supply off before connecting it to, or removing it from a jig or fixture, during the inspection process. Ground the IC during assembly steps as an antistatic measure. Use similar precaution when transporting and storing the IC.

7. IC pin input (Fig. 42)

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements to keep them isolated. P-N junctions are formed at the intersection of these P layers with the N layers of other elements, creating a parasitic, creating a parasitic diode or transistor. For example, the relation between each potential is as follows:

- When GND>pin A and GND>pin B, the P-N junction operates as a parasitic diode.
- When pin B >GND>pin A, the P-N junction operates as a parasitic transistor. Parasitic diodes can occur inevitably in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Accordingly, methods by which parasitic diodes operate, such as applying a voltage that is lower than the GND (P substrate) voltage to an input pin, should not be used.

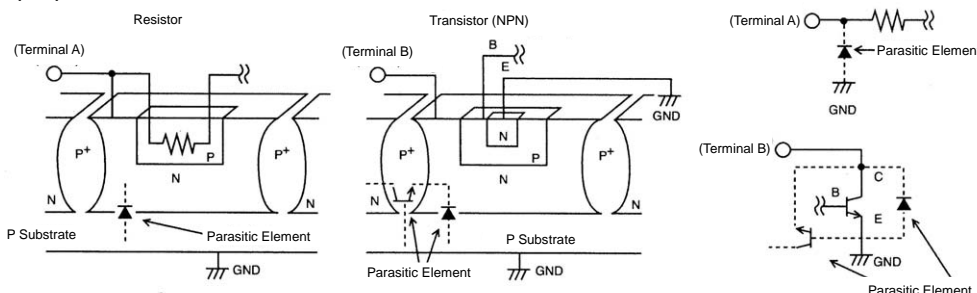


Fig.42 Typical simple construction of monolithic IC



## 8. GND wiring pattern

It is recommended to separate the large-current GND pattern from the small-signal GND pattern and establish a single ground at the reference point of the set PCB, so that resistance to the wiring pattern and voltage fluctuations due to a large current will cause on fluctuations in voltages of the small-signal GND. Prevent fluctuations in the GND wiring pattern of external parts.

## 9. Temperature protection (thermal shut down) circuit

This IC has a built-in temperature protection circuit to prevent the thermal destruction of the IC. As described above, be sure to use this IC within the power dissipation range. Should a condition exceeding the power dissipation range continue, the chip temperature  $T_j$  will rise to activate the temperature protection circuit, thus turning OFF the output power element. Then, when the tip temperature  $T_j$  falls, the circuit will be automatically reset. Furthermore, if the temperature protection circuit is activated under the condition exceeding the absolute maximum ratings, do not attempt to use the temperature protection circuit for set design.

10. On the application shown below, if there is a mode in which  $V_{IN}$  and each pin potential are inverted, for example, if the  $V_{IN}$  is short-circuited to the Ground with external diode charged, internal circuits may be damaged. To avoid damage, it is recommended to insert a backflow prevention diode in the series with  $V_{IN}$  or a bypass diode between each pin and  $V_{IN}$ .

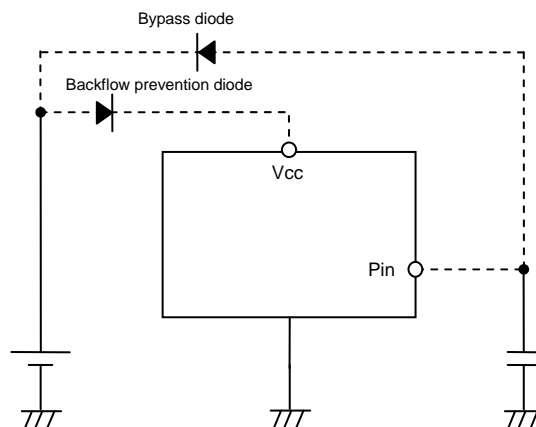
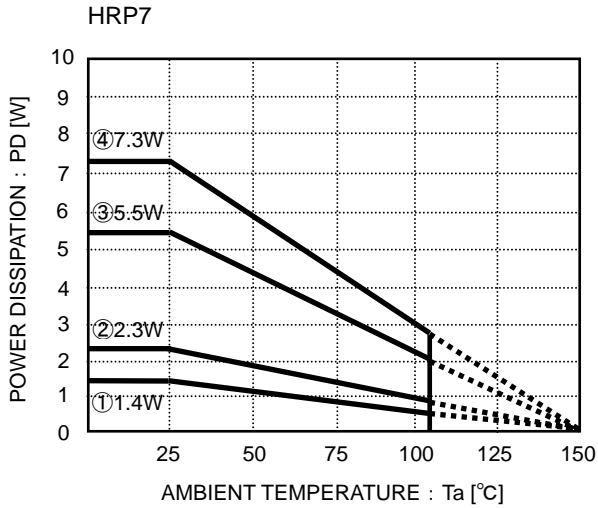


Fig.43

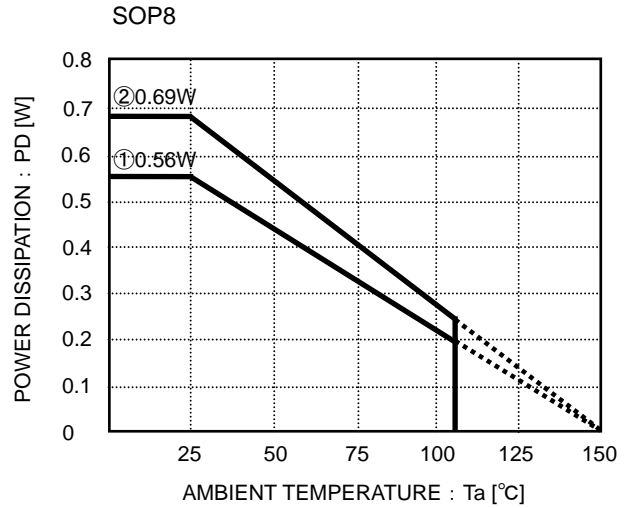
11. This IC is designed that over current protection circuit operates at start up and normal operation. Therefore at start up when this IC's total load current (sum of load current and charge current to output capacitor) is exceeded 2A(BD9006F/HFP,BD9007F/HFP Minimum load current ability) ,4A(BD9009HFP Minimum load current ability), over current protection circuit operates, and this IC's start up times are excessive time.If this case is occurred, output capacitor is recommended to change small value.
12. When this IC starts up with output-GND short, SW output current is exceeded 2A(BD9006F/HFP,BD9007F/HFP) , 4A(BD9009HFP), and this IC may be destroyed. When VIN input voltage is under 7V with output-GND short, over current protection may don't operates.Please don't use this IC in these cases.

● Thermal reduction characteristics



- ① Single piece of IC  
PCB Size: 70x70x1.6mm<sup>3</sup> (PCB incorporates thermal via)  
Copper foil area on the front side of PCB: 10.5x10.5mm<sup>2</sup>
- ② 2-layer PCB (Copper foil area on the reverse side of PCB: 15x15mm<sup>2</sup>)
- ③ 2-layer PCB (Copper foil area on the reverse side of PCB: 70x70mm<sup>2</sup>)
- ④ 4-layer PCB (Copper foil area on the reverse side of PCB: 70x70mm<sup>2</sup>)

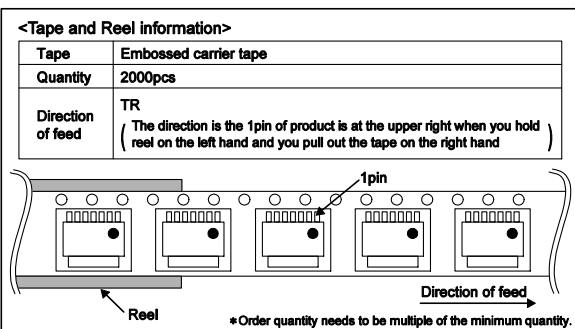
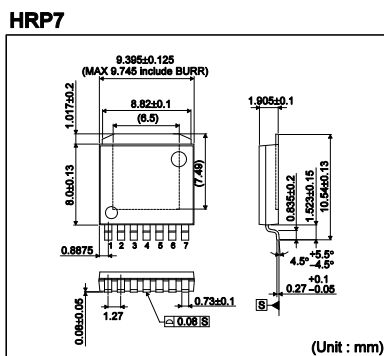
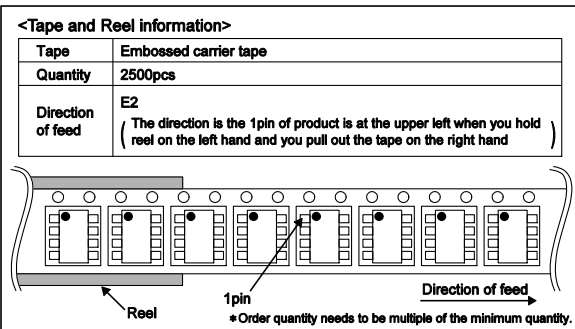
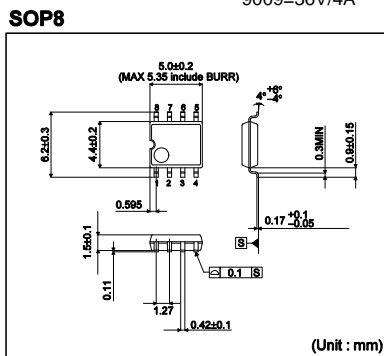
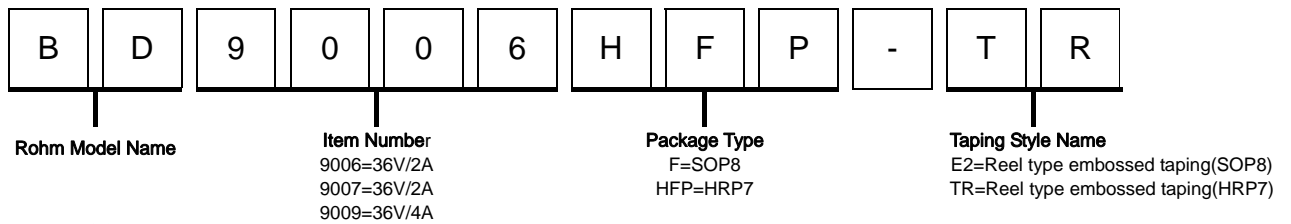
Fig.44



- ① Single piece of IC
- ② When mounted on ROHM standard PCB  
(Glass epoxy PCB of 70mmx70mmx1.6mm)

Fig.45

● Ordering Name Selection



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Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: [ocean@oceanchips.ru](mailto:ocean@oceanchips.ru)

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А